

300 mA very low dropout linear regulator IC



DFN4 1x1

Features

- Input voltage from 1.5 to 5.5 V
- Ultra low dropout voltage (135 mV typ. at 300 mA load)
- Very low quiescent current (28 μ A typ. at no load, 0.03 μ A typ. in off mode)
- Internal current fold-back
- Output voltage tolerance: $\pm 1\%$ @ 25 $^{\circ}$ C
- 300 mA guaranteed output current
- High PSRR: 75 dB@1 kHz
- Wide range of output voltages available on request: from 0.8 V up to 5.0 V in 50 mV step
- Logic-controlled electronic shutdown
- Internal soft-start
- Optional output voltage discharge feature
- Compatible with ceramic capacitor $C_{OUT} = 0.47\ \mu$ F
- Thermal protection
- Available in DFN4 1x1
- Operating temperature range: -40 $^{\circ}$ C to 125 $^{\circ}$ C

Description

The [LD59030](#) high accuracy voltage regulator provides 300 mA of maximum current from an input voltage ranging from 1.5 V to 5.5 V, with a typical dropout voltage of 135 mV at $V_{OUT} = 3.3$ V.

It is available in DFN4 1x1 package, allowing the maximum space saving.

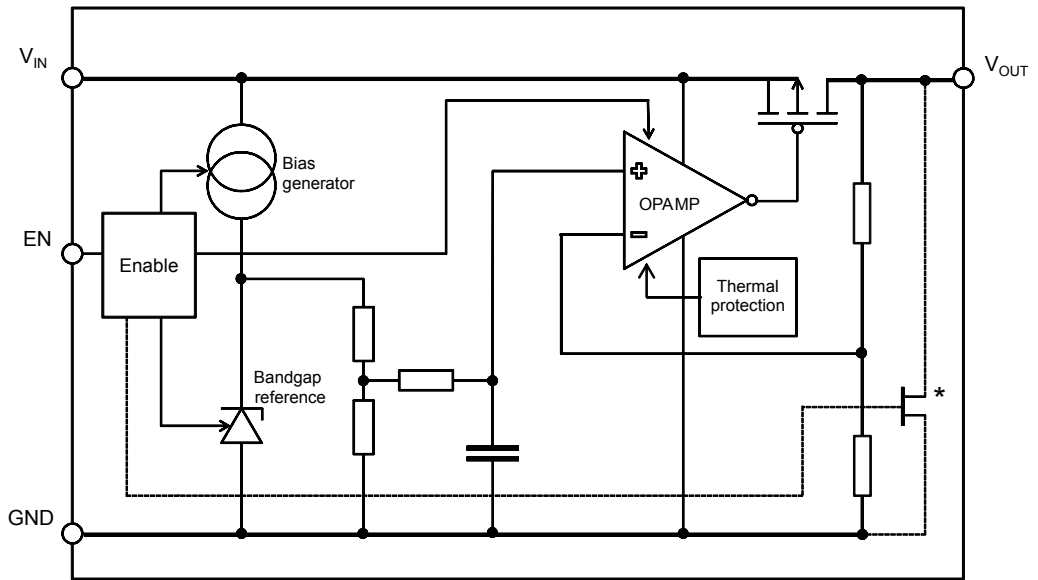
The device works with a ceramic capacitor on the output. The ultra-low drop voltage, low quiescent current and low noise features, together with the internal soft-start circuit and output current fold-back protection, make the [LD59030](#) suitable for low power battery-operated applications.

An enable logic control function puts the [LD59030](#) in shutdown mode allowing a total current consumption lower than 0.03 μ A.

Maturity status link

[LD59030](#)

1 Diagram

Figure 1. Block diagram


AM13852V1

Note: The output discharge MOSFET is optional.

2 Pin configuration

Figure 2. Pin connection (top view)

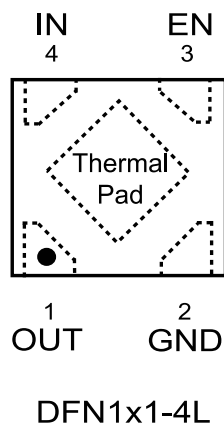
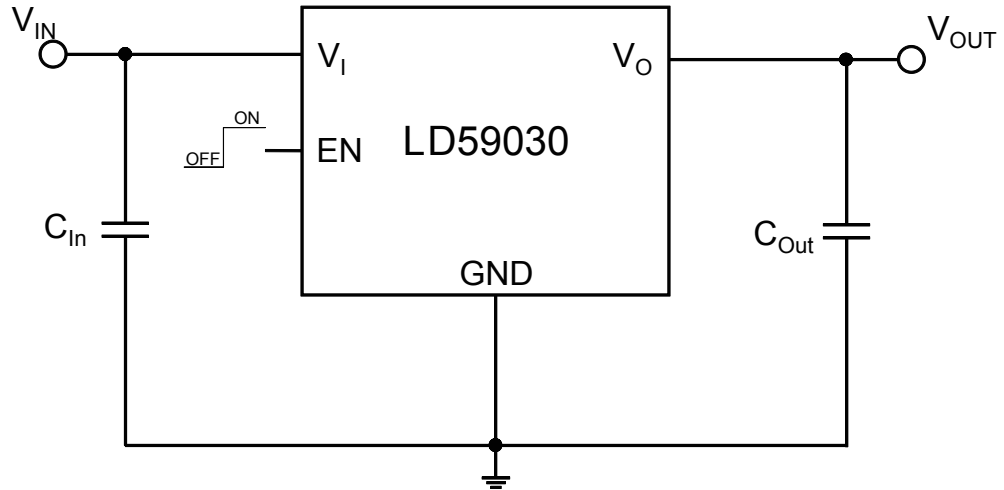


Table 1. Pin description

Pin n° DFN4 1x1	Symbol	Function
1	OUT	Output voltage
2	GND	Common ground
3	EN	Enable pin logic input: Low = shutdown, High = active
4	IN	Input voltage
Thermal pad	-	Connect to GND or floating

3 Typical application

Figure 3. Typical application circuit



4 Maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{IN}	Input voltage	- 0.3 to 7	V
V_{OUT}	Output voltage	- 0.3 to $V_{IN} + 0.3$	V
V_{EN}	Enable input voltage	- 0.3 to 7	V
I_{OUT}	Output current	Internally limited	mA
P_D	Power dissipation	Internally limited	mW
T_{STG}	Storage temperature range	- 40 to 150	°C
T_{OP}	Operating junction temperature range	- 40 to 125	°C

Note: Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. All values are referred to GND.

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R_{thJA}	Thermal resistance junction-ambient	140	°C/W

Table 4. ESD Performance

Symbol	Parameter	Test conditions	Value	Unit
ESD	ESD Protection voltage	HBM	2	kV
		CDM	500	V

5 Electrical characteristics

$T_J = 25\text{ }^\circ\text{C}$, $V_{IN} = V_{OUT(NOM)} + 1\text{ V}$, $C_{IN} = C_{OUT} = 1\text{ }\mu\text{F}$, $I_{OUT} = 1\text{ mA}$, $V_{EN} = V_{IN}$, unless otherwise specified.

Table 5. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_{IN}	Operating input voltage		1.5		5.5	V
V_{OUT}	V_{OUT} accuracy	$I_{OUT} = 1\text{ mA}$, $T_J = 25\text{ }^\circ\text{C}$	-1		1	%
		$I_{OUT} = 1\text{ mA}$, $-40\text{ }^\circ\text{C} < T_J < 85\text{ }^\circ\text{C}$	-2		2	%
ΔV_{OUT}	Static line regulation ⁽¹⁾	$V_{OUT(NOM)} + 1\text{ V} \leq V_{IN} \leq 5.5\text{ V}$, $I_{OUT} = 10\text{ mA}$		0.015		%V
		$-40\text{ }^\circ\text{C} < T_J < 85\text{ }^\circ\text{C}$			0.05	
ΔV_{OUT}	Static load regulation	$I_{OUT} = 0\text{ mA to } 300\text{ mA}$		-20		mV
		$I_{OUT} = 0\text{ mA to } 300\text{ mA}$ $-40\text{ }^\circ\text{C} < T_J < 85\text{ }^\circ\text{C}$		-0.004	-0.01	%/mA
V_{DROP}	Dropout voltage	$I_{OUT} = 30\text{ mA}$, $V_{OUT} = 2.8\text{ V}$		20		mV
		$I_{OUT} = 300\text{ mA}$, $V_{OUT} = 2.8\text{ V}$ $-40\text{ }^\circ\text{C} < T_J < 85\text{ }^\circ\text{C}$		155	230	
e_N	Output noise voltage	10 Hz to 100 kHz, $I_{OUT} = 10\text{ mA}$, $V_{OUT} = 1.8\text{ V}$		70		μV_{RMS}
SVR	Supply voltage rejection	$V_{IN} = V_{OUT(NOM)} + 1\text{ V} \pm V_{RIPPLE}$ $V_{RIPPLE} = 0.2\text{ V}$ Freq. = 1 kHz $I_{OUT} = 30\text{ mA}$		75		dB
		$V_{IN} = V_{OUT(NOM)} + 1\text{ V} \pm V_{RIPPLE}$ $V_{RIPPLE} = 0.2\text{ V}$ Freq. = 100 kHz $I_{OUT} = 30\text{ mA}$		55		
I_Q	Quiescent current	$I_{OUT} = 0\text{ mA}$		28	40	μA
		$I_{OUT} = 300\text{ mA}$		305		
$I_{Standby}$	Standby current	V_{IN} input current in OFF MODE: $V_{EN} = \text{GND}$		0.03	1	μA
I_{LIM}	Current limit	$V_{OUT} = 0.9 \times V_{OUT(NOM)}$		500		mA
I_{SC}	Short circuit current	$V_{OUT} = 0$ (foldback protection)	120	170		mA
R_{ON}	Output voltage discharge MOSFET	(LD59030DT version) $I_{OUT} = 1\text{ mA}$		120		Ω
V_{EN}	Enable input logic low	$V_{IN} = 1.5\text{ V to } 5.5\text{ V}$ $-40\text{ }^\circ\text{C} < T_J < 85\text{ }^\circ\text{C}$			0.4	V
	Enable input logic high	$V_{IN} = 1.5\text{ V to } 5.5\text{ V}$ $-40\text{ }^\circ\text{C} < T_J < 85\text{ }^\circ\text{C}$	1			
I_{EN}	Enable pin input current	$V_{EN} = V_{IN}$			100	nA
$T_{ON}^{(2)}$	Turn on time			145		μs
T_{SHDN}	Thermal shutdown			160		$^\circ\text{C}$
	Hysteresis			20		

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
C _{OUT}	Output capacitor	Capacitance (see Figure 15. Stability area vs. (C _{OUT} , ESR))	0.47		22	μF

1. Not applicable for $V_{OUT(NOM)} > 4.5\text{ V}$
2. Turn-on time is time measured between the enable input just exceeding VEN high value and the output voltage just reaching 95 % of its nominal value

6 Application information

6.1 Soft-start function

The LD59030 has an internal soft start circuit. By increasing the startup time up to 145 μs , without the need of any external soft start capacitor, this feature is able to keep the regulator inrush current at startup under control.

6.2 Output discharge function

The LD59030 integrates a MOSFET connected between V_{OUT} and GND. This transistor is activated when the EN pin goes to low logic level and has the function to quickly discharge the output capacitor when the device is disabled by the user.

The device is available with or without auto-discharge feature.

See [Section 9 Ordering information](#) for more details.

6.3 Dropout voltage

Table 6. Dropout voltage at $I_{\text{OUT}} = 300 \text{ mA}$

Output voltage [V]	Typical value [mV] $T_J = 25^\circ\text{C}$	Max value [mV] $-40^\circ\text{C} < T_J < 85^\circ\text{C}$
1.05	400	550
1.2	330	490
1.5	260	390
1.8	180 ⁽¹⁾	210 ⁽¹⁾
2.5	165	253
2.8	155	230
3.0	145	220
3.1	140	210
3.3	135	200

1. Measured value.

6.4 Input and output capacitors

The LD59030 requires external capacitors to assure the regulator control loop stability.

Any good quality ceramic capacitor can be used but, the X5R and the X7R are suggested since they guarantee a very stable combination of capacitance and ESR over the whole temperature range.

Locating the input/output capacitors as close as possible to the relative pins is recommended.

The LD59030 requires an input capacitor with a minimum value of 1 μF . This capacitor must be located as close as possible to the input pin of the device and returned to a clean analog ground.

The control loop of the LD59030 is designed to work with an output ceramic capacitor.

This capacitor must meet the requirements of minimum capacitance and equivalent series resistance (ESR), as shown in [Figure 15. Stability area vs. \(\$C_{\text{OUT}}\$, ESR\)](#). To assure stability, the output capacitor must maintain its ESR and capacitance in the stable region, over the full operating temperature range.

In order to keep stability in all operating conditions (temperature, input voltage and load variations), a minimum output capacitor of 0.47 μF is recommended.

The suggested combination of 1 μF input and output capacitors offers a good compromise among the stability of the regulator, optimum transient response and total PCB area occupation.

7 Typical characteristics

($C_{IN} = C_{OUT} = 1 \mu\text{F}$, V_{EN} to V_{IN} , $T_J = 25^\circ\text{C}$ unless otherwise specified)

Figure 4. Output voltage vs. temperature ($V_{OUT} = 1.8 \text{ V}$; $I_{OUT} = 1 \text{ mA}$)

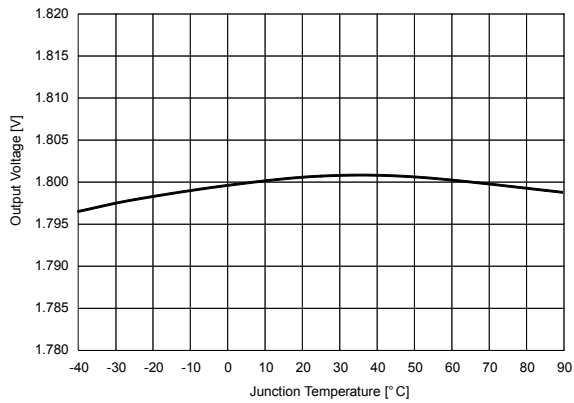


Figure 5. Output voltage vs. temperature ($V_{OUT} = 1.8 \text{ V}$; $I_{OUT} = 300 \text{ mA}$)

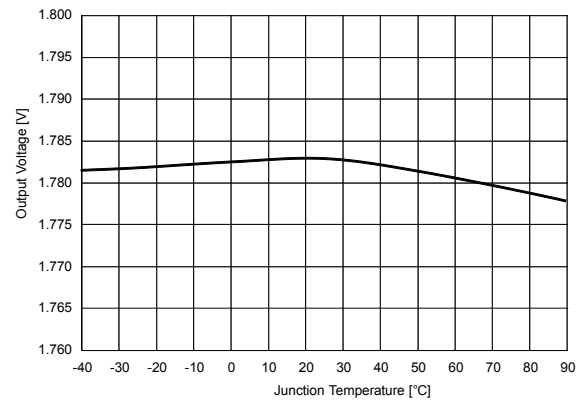


Figure 6. Line regulation vs. temperature ($V_{IN} = 2.8 \text{ V}$ to 5.5 V ; $V_{OUT} = 1.8 \text{ V}$; $I_{OUT} = 10 \text{ mA}$)

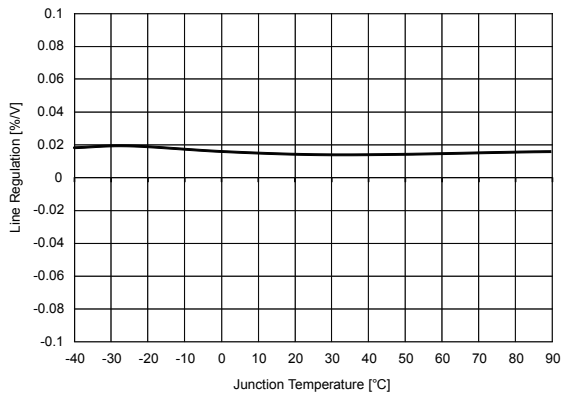


Figure 7. Load regulation vs. temperature ($V_{OUT} = 1.8 \text{ V}$; $I_{OUT} = 0$ to 300 mA)

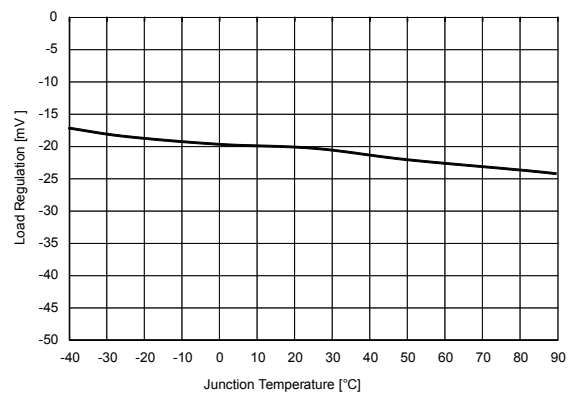


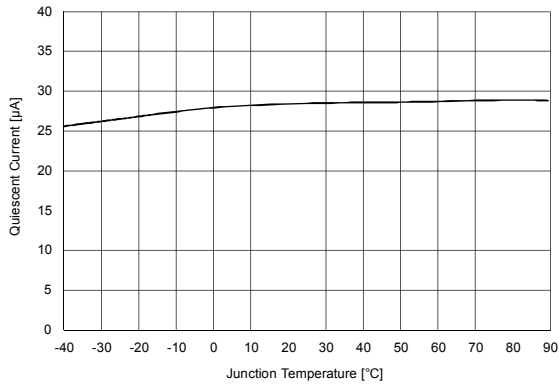
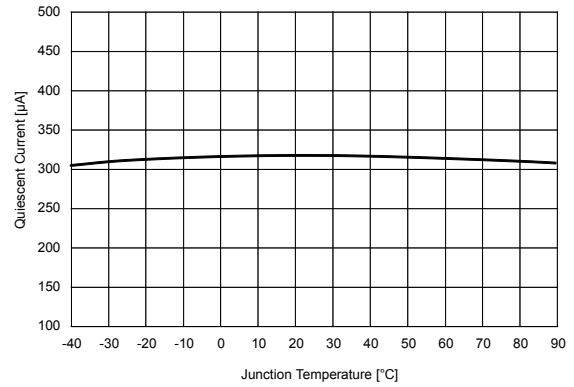
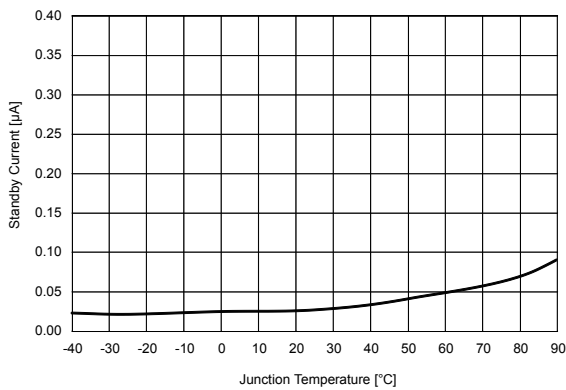
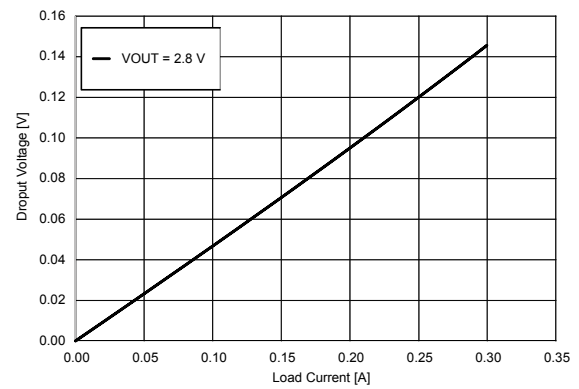
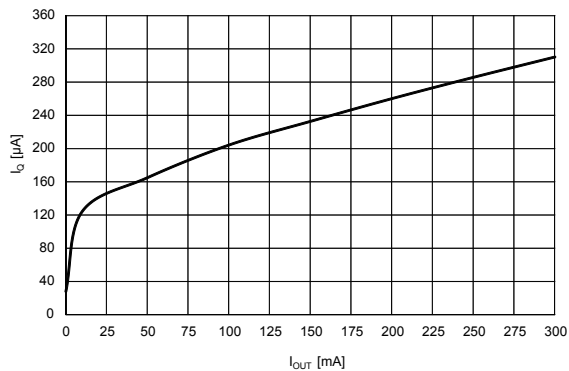
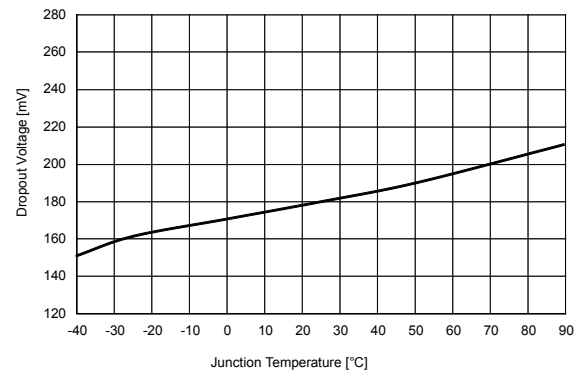
Figure 8. Quiescent current vs. temperature ($I_{OUT} = 0$ mA)

Figure 9. Quiescent current vs. temperature ($I_{OUT} = 300$ mA)

Figure 10. Shutdown current vs. temperature

Figure 11. Dropout voltage vs. load current

Figure 12. Quiescent current vs. output current ($V_{IN} = 2.8$ V; $V_{OUT} = 1.8$ V)

Figure 13. Dropout voltage vs. temperature ($V_{OUT} = 1.8$ V; $I_{OUT} = 300$ mA)


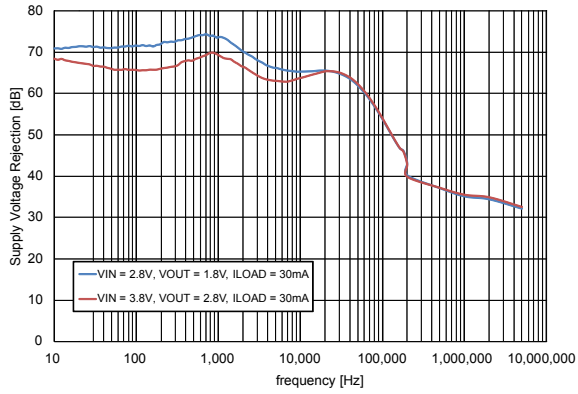
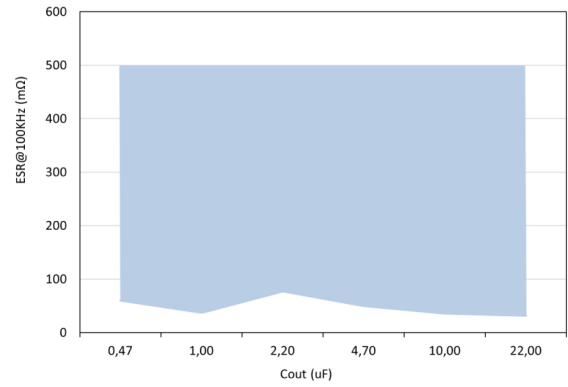
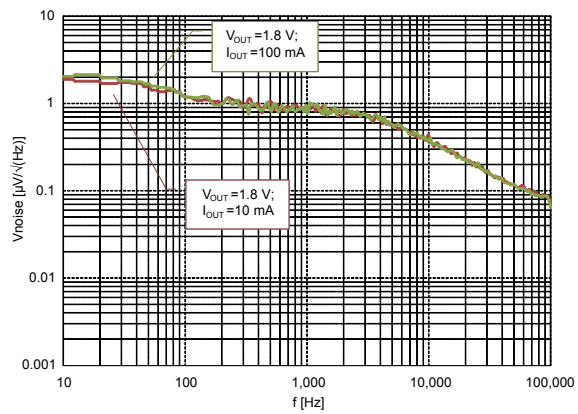
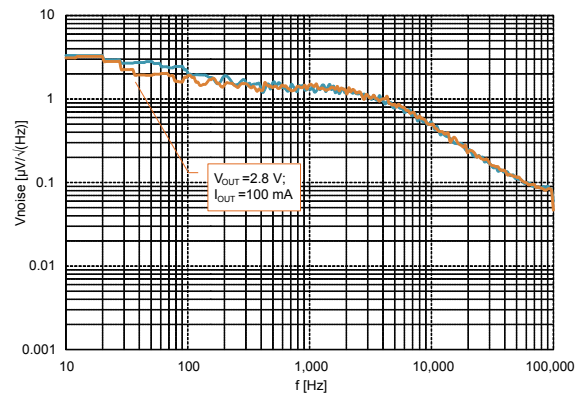
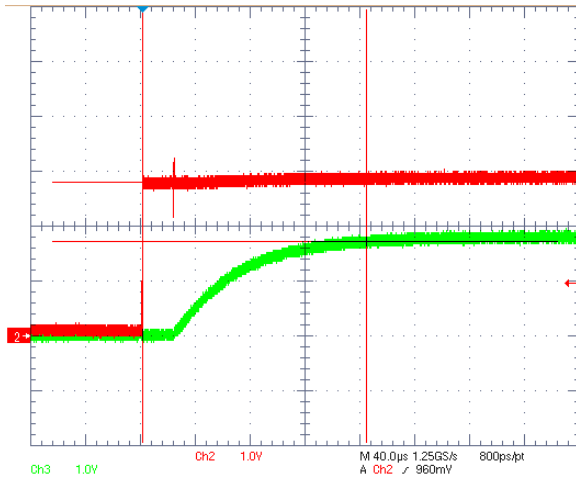
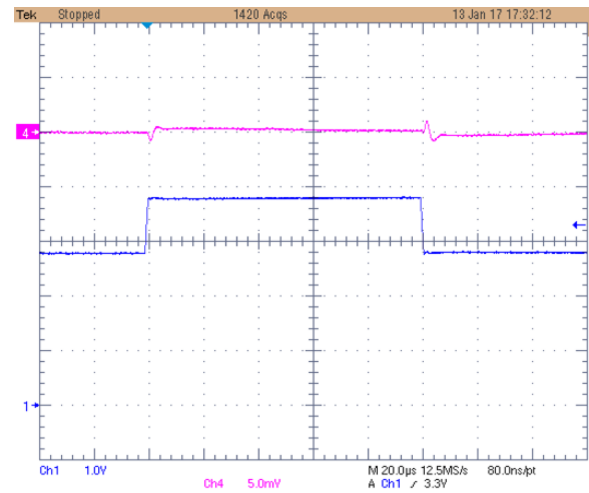
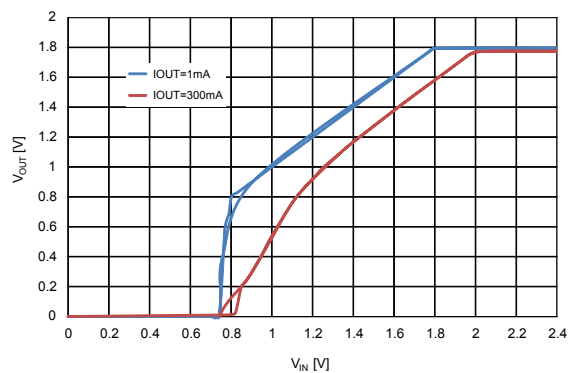
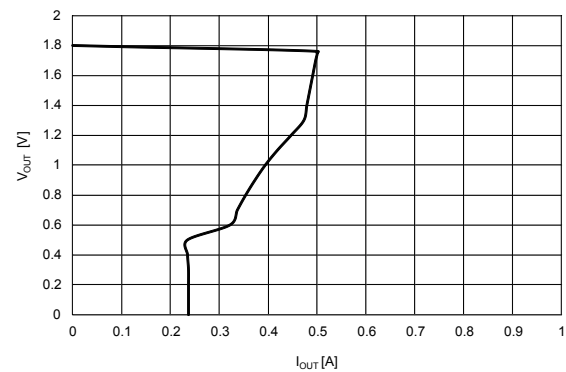
Figure 14. Supply voltage rejection vs. frequency

Figure 15. Stability area vs. (C_{OUT}, ESR)

Figure 16. Output noise spectral density (V_{OUT} = 1.8 V)

Figure 17. Output noise spectral density (V_{OUT} = 2.8 V)


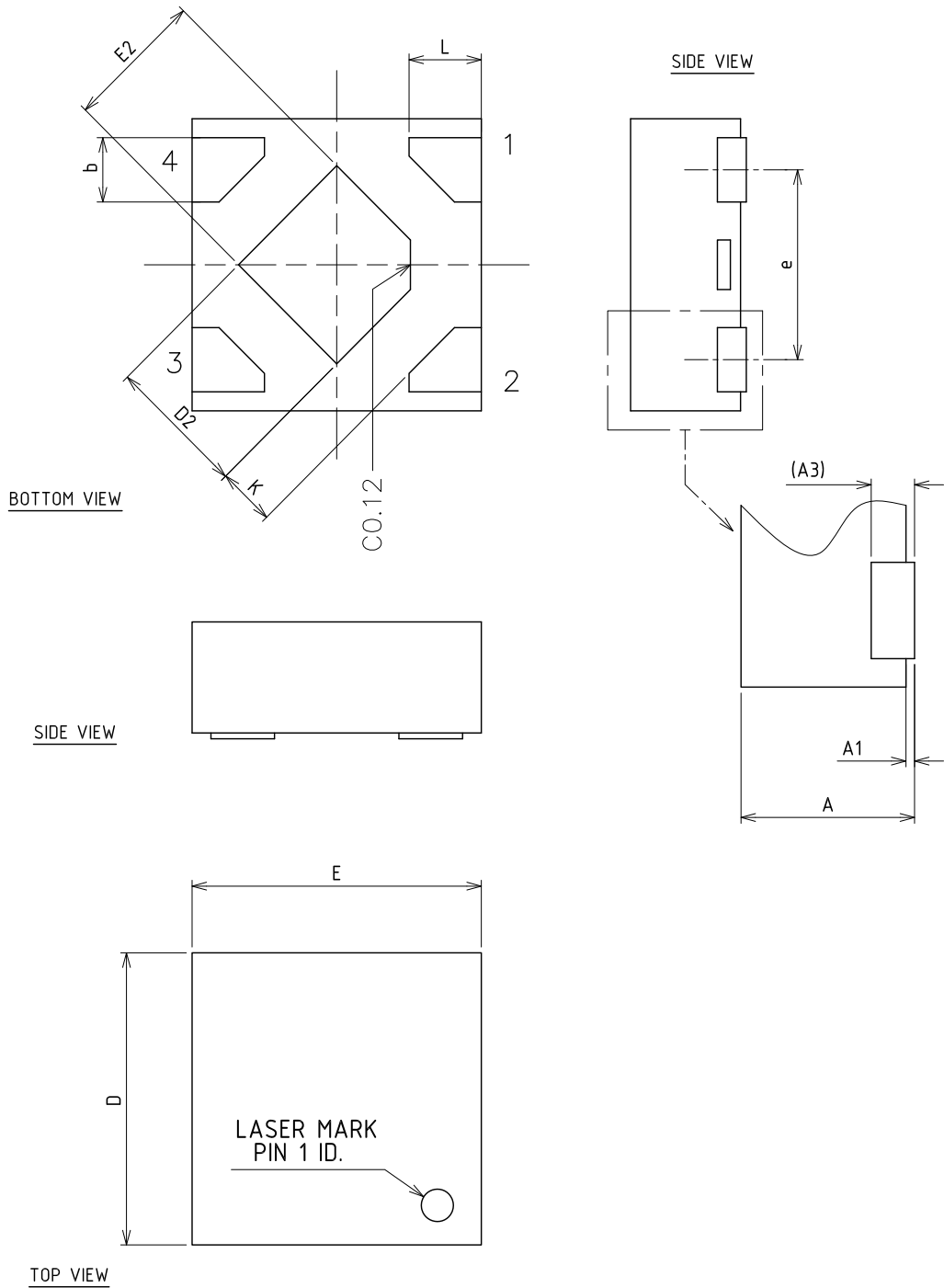
Figure 18. Turn-on Time ($V_{OUT} = 1.8\text{ V}$; $I_{OUT} = 0\text{ A}$, $V_{IN} = 2.8\text{ V}$, $t_r = t_f = 1\text{ }\mu\text{s}$)

Figure 19. Line transient ($V_{OUT} = 1.8\text{ V}$; $I_{OUT} = 10\text{ mA}$, $t_r = t_f = 1\text{ }\mu\text{s}$)

Figure 20. Output voltage vs. input voltage

Figure 21. Output voltage vs. output current


8 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

8.1 DFN4 1x1 package info

Figure 22. DFN4 1x1 package outline

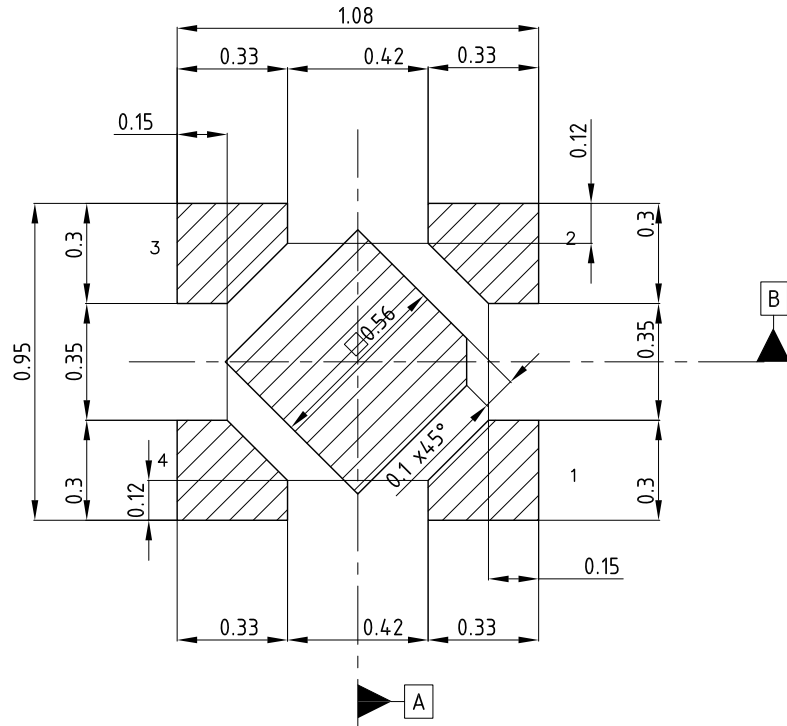


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Table 7. DFN4 1x1 mechanical data

Dim.	mm.		
	Min.	Typ.	Max.
A	0.34	0.37	0.40
A1	0	0.02	0.05
A3		0.10	
b	0.17	0.22	0.27
D	0.95	1.00	1.05
D2	0.43	0.48	0.53
E	0.95	1.00	1.05
E2	0.43	0.48	0.53
e		0.65	
L	0.20	0.25	0.30
K	0.15		

Figure 23. DFN4 1x1 recommended footprint

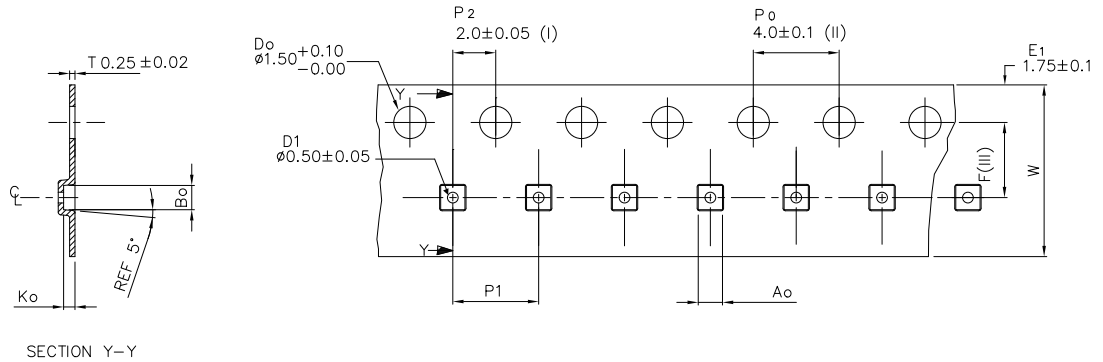


Notes:

- 1) This footprint is able to ensure insulation up to 10 Vrms (according to CEI IEC 664-1)
- 2) The device must be positioned within $\oplus 0.02$ A B

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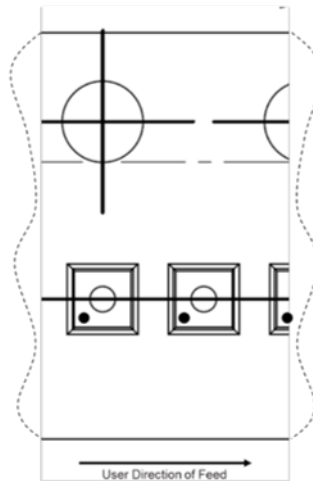
8.2 DFN4 1x1 packing information

Figure 24. Tape dimensions


A _o	1.13 +/−0.05
B _o	1.13 +/−0.05
K _o	0.53 +/−0.05
F	3.50 +/−0.05
P ₁	4.00 +/−0.10
W	8.00 +0.3/−0.1

- (I) Measured from centreline of sprocket hole to centreline of pocket.
- (II) Cumulative tolerance of 10 sprocket holes is ± 0.20 .
- (III) Measured from centreline of sprocket hole to centreline of pocket.
- (IV) Other material available.
- (V) Typical SR of form tape Max. 10⁸ OHM/SR

ALL DIMENSIONS IN MILLIMETRES UNLESS OTHERWISE STATED.



9 Ordering information

Table 8. Order code

Order code	Output voltage (V)	Auto-discharge	Marking
LD59030DTPU105R	1.05	Yes	JQ
LD59030TPU105R		No	KQ
LD59030DTPU12R	1.2	Yes	J5
LD59030TPU12R		No	K5
LD59030DTPU18R	1.8	Yes	J7
LD59030TPU18R		No	K7
LD59030DTPU25R	2.5	Yes	JA
LD59030TPU25R		No	KA
LD59030DTPU28R	2.8	Yes	JC
LD59030TPU28R		No	KC
LD59030DTPU30R	3.0	Yes	JF
LD59030TPU30R		No	KF
LD59030DTPU33R	3.3	Yes	JJ
LD59030TPU33R		No	KJ

Revision history

Table 9. Document revision history

Date	Revision	Changes
28-Aug-2017	1	Initial release.
03-Nov-2017	2	Datasheet promoted from preliminary data to datasheet. Update Figure 15: "Stability area vs. (CO _{UT} , ESR)".
01-Jun-2018	3	Updated: Figure 24. Tape dimensions.
31-Jul-2018	4	Updated: output voltage in Table 6. Dropout voltage at I _{OUT} = 300 mA.

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